

# HD74LVC74

## Dual D-type Flip Flops with Preset and Clear

REJ03D0347-0400Z (Previous ADE-205-066C (Z)) Rev.4.00 Jul. 22, 2004

#### Description

The HD74LVC74 has independent data, preset, clear, and clock inputs Q and  $\overline{Q}$  outputs in a 14 pin package. The logic level present at the data input is transferred to the output during the positive going transition of the clock pulse. Preset and clear are independent of the clock and accomplished by a low level at the appropriate input. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

#### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.0 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- High output current  $\pm 24$  mA (@V<sub>CC</sub> = 3.0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVC74FPEL	SOP-14 pin (JEITA)	FP-14DAV	FP	EL (2,000 pcs/reel)
HD74LVC74TELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

#### **Function Table**

Inputs				Outputs	
PR	CLR	CK	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	Χ	Χ	L	Н
L	L	Χ	Χ	H *1	H *1
Н	Н	<b>↑</b>	Н	Н	L
Н	Н	<b>↑</b>	L	L	Н
Н	Н	L	Χ	$Q_0$	$\overline{Q}_0$
Н	Н	Н	X	$Q_0$	$\overline{Q}_0$
Н	Н	$\downarrow$	X	$Q_0$	$\overline{Q}_0$

H: High level

L: Low level

X: Immaterial

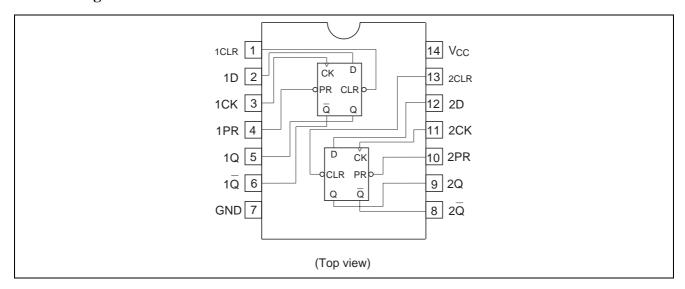
↓: High to Low transition

1: Low to high transition

Q<sub>0</sub>: Level to Q before the indicated steady input conditions was established.

Note: 1. Q and  $\overline{Q}$  will remain high as long as preset and clear are low, but Q and  $\overline{Q}$  are unpredictable, if preset and clear go high simultaneously.

#### **Pin Arrangement**



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>CC</sub>	-0.5 to 6.0	V	
Input diode current	I <sub>IK</sub>	<b>–</b> 50	mA	$V_1 = -0.5 \text{ V}$
Input voltage	VI	-0.5 to 6.0	V	
Output diode current	I <sub>OK</sub>	<b>–</b> 50	mA	$V_{O} = -0.5 \text{ V}$
		50	<u> </u>	$V_{O} = V_{CC} + 0.5 \text{ V}$
Output voltage	Vo	$-0.5$ to $V_{CC}$ +0.5	V	
Output current	Ιο	±50	mA	
V <sub>CC</sub> , GND current / pin	I <sub>CC</sub> or I <sub>GND</sub>	100	mA	
Storage temperature	Tstg	-65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

#### **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V <sub>CC</sub>	1.5 to 5.5	V	Data retention
		2.0 to 5.5		At operation
Input / output voltage	Vı	0 to 5.5	V	PR, CLR, CK, D
	Vo	0 to V <sub>CC</sub>		Q, Q
Operating temperature	Та	-40 to 85	°C	
Output current	Іон	-12	mA	V <sub>CC</sub> = 2.7 V
		-24 <sup>*2</sup>		V <sub>CC</sub> = 3.0 V to 5.5 V
	loL	12	mA	V <sub>CC</sub> = 2.7 V
		24 *2		V <sub>CC</sub> = 3.0 V to 5.5 V
Input rise / fall time *1	t <sub>r</sub> , t <sub>f</sub>	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

2. Duty cycle  $\leq 50\%$ 

## HD74LVC74

## **Electrical Characteristics**

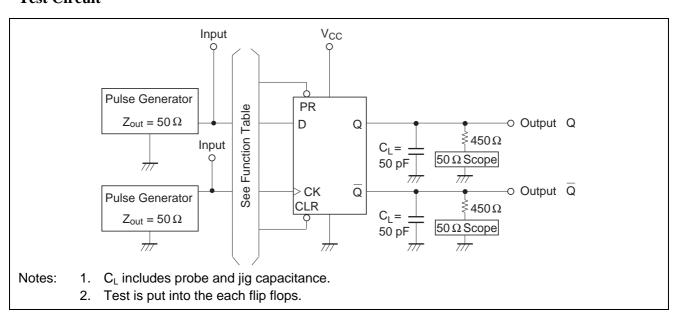
 $Ta = -40 \text{ to } 85^{\circ}C$ 

			14 - 1	0 10 00 0		
Item	Symbol	V <sub>CC</sub> (V)	Min	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.7 to 3.6	2.0	_	V	
		4.5 to 5.5	V <sub>CC</sub> ×0.7	_	_	
	V <sub>IL</sub>	2.7 to 3.6	_	0.8	V	
		4.5 to 5.5	_	V <sub>CC</sub> ×0.3	_	
Output voltage	$V_{OH}$	2.7 to 5.5	V <sub>CC</sub> -0.2	_	V	$I_{OH} = -100 \mu A$
		2.7	2.2	_	_	$I_{OH} = -12 \text{ mA}$
		3.0	2.4	_	_	
		3.0	2.0	_	_	$I_{OH} = -24 \text{ mA}$
		4.5	3.8	_	_	
	V <sub>OL</sub>	2.7 to 5.5	_	0.2	V	I <sub>OL</sub> = 100 μA
		2.7	_	0.4	_	I <sub>OL</sub> = 12 mA
		3.0	_	0.55	_	I <sub>OL</sub> = 24 mA
		4.5	_	0.55	_	
Input current	I <sub>IN</sub>	0 to 5.5	_	±5.0	μA	V <sub>IN</sub> = 5.5 V or GND
Quiescent supply current	I <sub>CC</sub>	5.5	_	20	μA	V <sub>IN</sub> = V <sub>CC</sub> or GND
	$\Delta I_{CC}$	3.0 to 3.6	_	500	μΑ	$V_{IN}$ = one input at $(V_{CC}-0.6)V$ , other inputs at $V_{CC}$ or GND

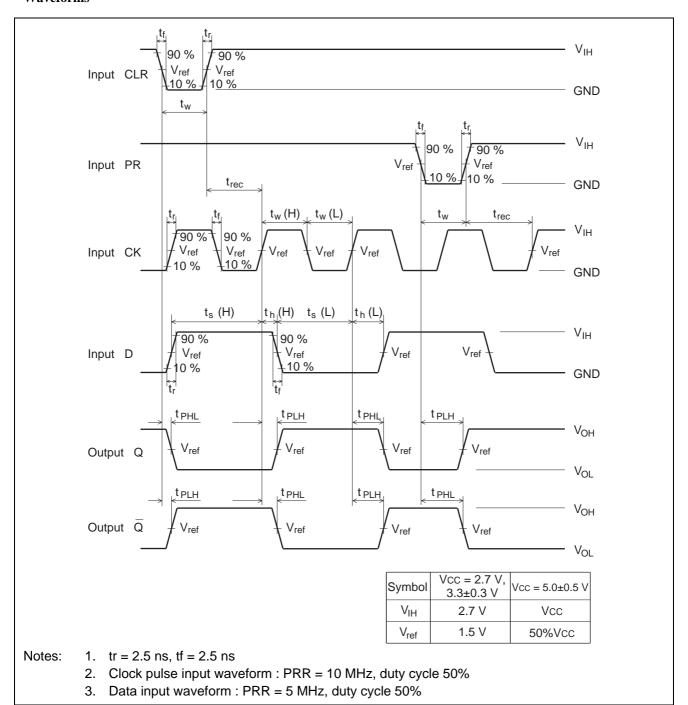
## **Switching Characteristics**

			Ta = -40 to 85°C				From	То
Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	(Input)	(Output)
Maximum clock frequency	$f_{\text{max}}$	2.7	150.0	_	_	MHz		
		3.3±0.3	150.0	_	_			
		5.0±0.5	150.0	_	_			
Propagation delay time	t <sub>PLH</sub>	2.7	_	6.0	9.0	ns	CLK	Q, Q
	$t_{PHL}$	3.3±0.3	1.5	5.0	8.0			
		5.0±0.5	_	4.0	6.5			
	t <sub>PLH</sub>	2.7	_	6.5	9.0	ns	PR or CLR	Q, Q
	$t_{PHL}$	3.3±0.3	1.5	5.0	8.0			
		5.0±0.5	_	4.0	6.5			
Setup time	t <sub>su</sub>	2.7	4.0	_	_	ns		
		3.3±0.3	3.0	_	_			
		5.0±0.5	3.0	_	_			
Hold time	t <sub>h</sub>	2.7	2.0	_	_	ns		
		3.3±0.3	2.0	_	_			
		5.0±0.5	2.0	_	_			
Pulse width	t <sub>w</sub>	2.7	4.0	_	_	ns	CK	
		3.3±0.3	4.0	_	_			
		5.0±0.5	4.0	_	_			
		2.7	6.0	_	_		PR or CLR	
		3.3±0.3	5.0	_	_			
		5.0±0.5	4.0	_	_			
Recovery time	t <sub>rec</sub>	2.7	3.0	_	_	ns		
		3.3±0.3	2.0	_	_			
		5.0±0.5	2.0	_	_			
Input capacitance	C <sub>IN</sub>	2.7	_	3.0	_	pF		
Output capacitance	Со	2.7	_	15.0	_	pF		

#### **Test Circuit**

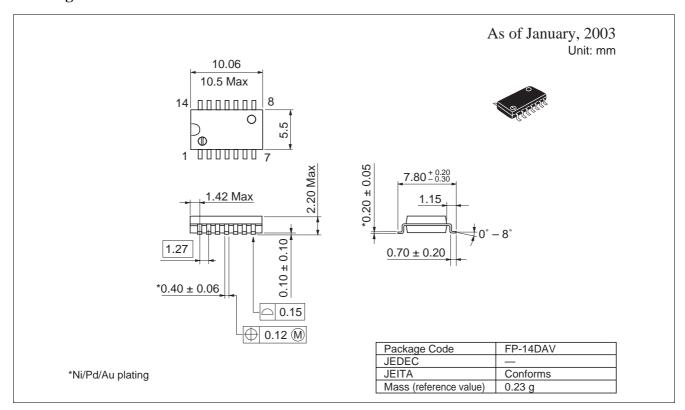


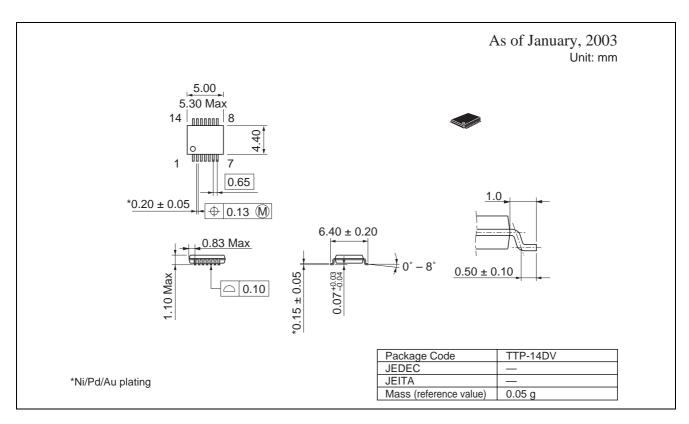
#### Waveforms



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#### **Package Dimensions**





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